N-Channel 650-V (D-S) MOSFET

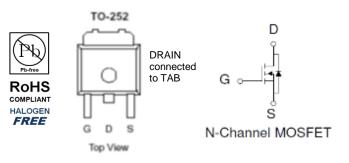
Key Features:

- Low r_{DS(on)} technology
- Low thermal impedance
- Fast switching speed

Typical Applications:

- Power Supplies
- Motor Drives
- Consumer Electronics

PRODUCT SUMMARY				
VDS (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)		
650	380 @ V _{GS} = 10V	9		



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Units	
Drain-Source Voltage			650	V	
Gate-Source Voltage		V _{GS}	±30	V	
Continuous Drain Current ^a	T _C =25°C	I _D	9	А	
Pulsed Drain Current ^b		I _{DM}	36	A	
Continuous Source Current (Diode Conduction) ^a	T _C =25°C	I _S	9	А	
Power Dissipation ^a	T _C =25°C	P _D	50	W	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 175	°C	

THERMAL RESISTANCE RATINGS			
Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient °	R _{θJA}	40	°C/W
Maximum Junction-to-Case	$R_{ extsf{ heta}JC}$	3	C/W

Notes

- a. Package Limited
- b. Pulse width limited by maximum junction temperature
- c. Surface Mounted on 1" x 1" FR4 Board.

Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static						
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$	1			V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 30 V$			±100	nA
Zero Gate Voltage Drain Current		$V_{DS} = 520 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1	uA
	I _{DSS}	$V_{DS} = 520 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			10	uA
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 10 V$	35			А
Drain-Source On-Resistance ^a	r _{DS(on)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 5 \text{ A}$			380	mΩ
Forward Transconductance ^a	g _{fs}	$V_{DS} = 50 \text{ V}, \text{ I}_{D} = 5 \text{ A}$		12		S
Diode Forward Voltage ^a	V_{SD}	$I_{S} = 5 \text{ A}, V_{GS} = 0 \text{ V}$		1		V
		Dynamic ^b				
Total Gate Charge	Q_g	$V_{DS} = 325 \text{ V}, V_{GS} = 10 \text{ V},$		20		
Gate-Source Charge	Q_gs	$V_{DS} = 525 V, V_{GS} = 10 V,$ $I_{D} = 5 A$		4.7		nC
Gate-Drain Charge	Q_gd	10 - 0 / 1		7.7		
Turn-On Delay Time	t _{d(on)}			9		
Rise Time	tr	$V_{DS} = 325 \text{ V}, \text{ R}_{L} = 65 \Omega,$ $I_{D} = 5 \text{ A},$		12		ne
Turn-Off Delay Time	t _{d(off)}	$V_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{GEN}} = 6 \Omega$		89		ns
Fall Time	t _f	GEN - TO V, TGEN O 12		53		
Input Capacitance	C _{iss}			663		
Output Capacitance	C _{oss}	$V_{DS} = 50, V_{GS} = 0 V, f = 1 Mhz$		109		pF
Reverse Transfer Capacitance	C _{rss}			11		

Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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0.8

20

30

1

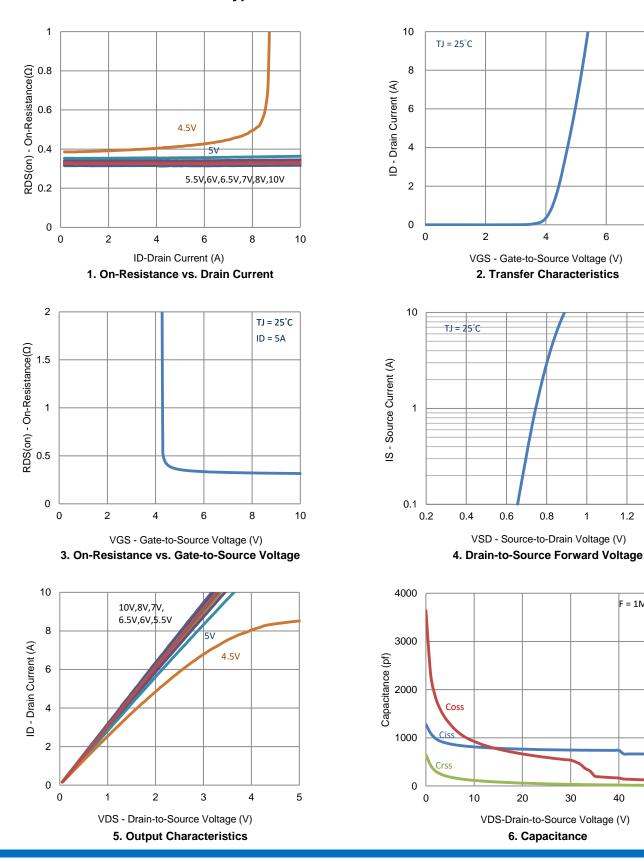
1.2

F = 1MHz

1.4

6

8

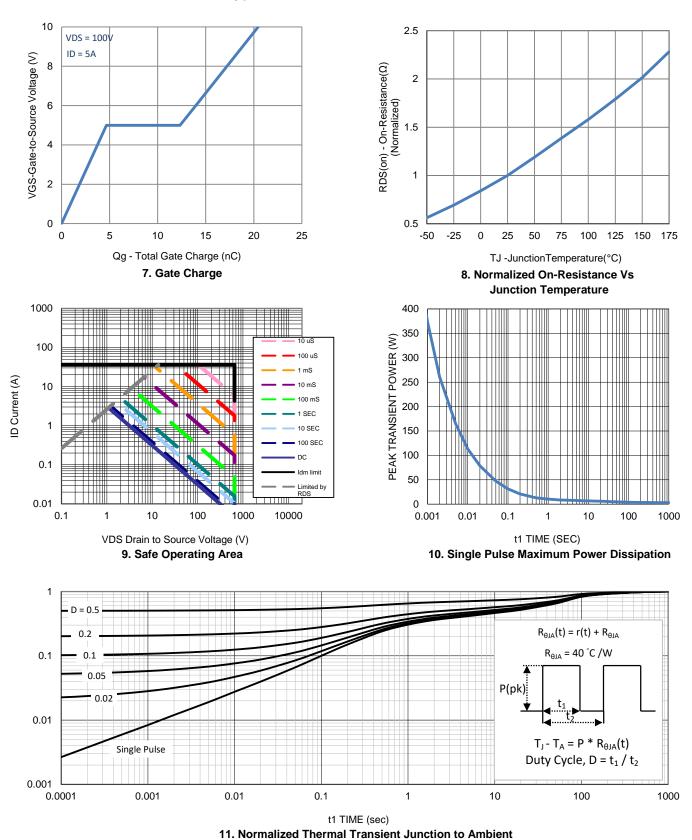


Typical Electrical Characteristics

Publication Order Number: DS_AM10N65-380D_1A

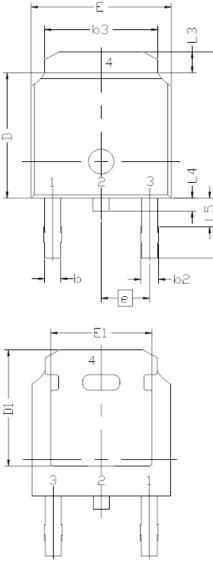
40

50

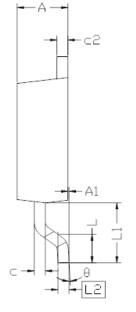


Package Information

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OVADE DIMENSIONAL REQMES					
SYMBOL	MIN		MAX		
E	6.40	6,60	6.731		
L	1.40	1.52	1.77		
L1		.743 RI			
L2		508 BS	-		
L3	0.89		1.27		
L4	0.64		1.01		
L5					
D	6.00	6.10	6.223		
Н	9.40	10.00	10.40		
b	0.64	0.76	0.88		
b2	0.77	0.84	1.14		
b3	5.21	5.34	5.46		
e		286 BS			
A	2.20	2.30	2.38		
A1	0		0.127		
\subset	0.45	0.50	0.60		
c2	0,45	0.50	0.58		
D1	5.30				
E1	4.40				
θ	0*		10*		

Note:

- 1. All Dimension Are In mm.
- 2. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
- 3. Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.